



PATENT
29925/37672

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Young-Hun Bae and
Won-Sung Park

Serial No.: 09/940,774

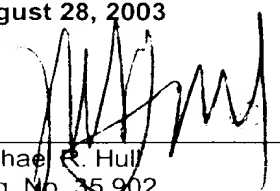
Filed: August 27, 2001

For: Method for Forming a Gate
of a High Integration
Semiconductor Device

Group Art Unit: 2823

Examiner: William M. Brewster

) I hereby certify that this paper is being
) deposited with the United States Postal
) Service as first class mail, postage
) prepaid, in an envelope addressed to:
) Commissioner for Patents, P.O. Box 1450
) Alexandria, Virginia 22313-1450 on
) **August 28, 2003**

) 
) Michael R. Hull
) Reg. No. 35,902
) Attorney for Applicants
)
)
)

AMENDMENT

Commissioner for Patents
P.O. Box 1450 Alexandria
Virginia 22313-1450

Dear Sir:

Please enter the following amendment in the above-referenced patent application.